TOSHIBA CMOS Digital Integrated Circuits Silicon Monolithic

TC9WMB1FK,TC9WMB2FK

TC9WMB1FK: 1024-Bit (128 × 8 Bit) 2-Wire Serial E^2 PROM TC9WMB2FK: 2048-Bit (256 × 8 Bit) 2-Wire Serial E^2 PROM

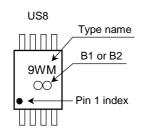
The TC9WMB1FK and TC9WMB2FK are electrically erasable/programmable nonvolatile memory (E 2 PROM).

Features

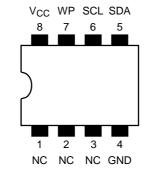
- 2-wire serial interface (I²C BUSTM) (Note 1)
- Single power supply
 - Read: V_{CC} = 1.8 to 5.5 V
 - Write: $V_{CC} = 2.3$ to 5.5 V
- Low power consumption: 5 μA (in standby state)
 : 0.5 mA (in read state)
- Operating frequency: 400 kHz (V_{CC} = 2.3 to 5.5 V)
- Byte write and page (8-byte) write
- Write protection
- Sequential read
- Write time: 10 ms (V_{CC} = 3.0 to 5.5 V)
 - $12 \text{ ms} (\text{V}_{\text{CC}} = 2.3 \text{ to } 2.7 \text{ V})$
 - Write endurance: 10⁵ times
- Data retention: 10 years
- Wide operating temperature range: -40 to 85°C
- Package: US8

Note 1: I²C BUS is a trademark of Royal Philips Electronics N.V.

Product Marking

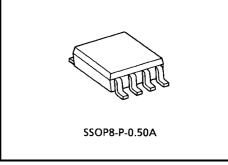








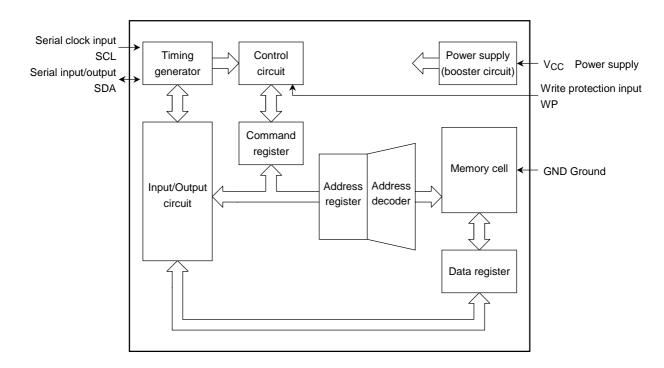
Purchase of TOSHIBA I²C components conveys a license under the Philips I²C Patent Rights to use these components in an I²C system, provided that the system conforms to the I²C Standard Specification as defined by Philips.



Weight: 0.01 g (typ.)



Block Diagram



Pin Function

Pin Name	Input/Output	Description
SCL	Input	Serial clock input Data is fetched on a rising edge of SCL. Data is output on a falling edge of SCL.
SDA	Input/output	Serial input/output This pin must be pulled up with a resistor because it is configured as an N-ch open-drain pin for output.
WP	Input	Write protection input A high on this input disables writing. A low on this input enables writing.
NC		No connection (not connected internally)
V _{CC}	Power supply	1.8 to 5.5 V (for reading) 2.3 to 5.5 V (for writing)
GND		0 V (GND)

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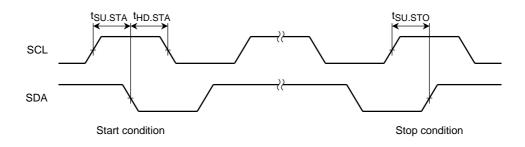
Functional Description

1. Start and Stop Conditions

When SCL is high, pulling SDA low produces a start condition and pulling SDA high produces a stop condition. Every instruction is started when a start condition occurs and terminated when a stop condition occurs.

During a read, a stop condition causes the read to terminate and the chip to enter the standby state. During a write, a stop condition causes the fetching of write data to terminate, after which writing starts automatically. Upon the completion of writing, the chip enters the standby state.

Two or more start conditions cannot be entered consecutively.





2. Modifying Data

Data on the SDA input can be modified while SCL is low. When SCL is high, modifying the SDA input means a start or stop condition.

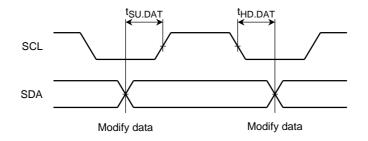


Figure 2

3. Acknowledge

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Data is transmitted and received in 8-bit units. The receiver sends an acknowledge signal by outputting a low on SDA in the 9th clock cycle, indicating that it has received data normally. The transmitter releases the bus in the 9th clock cycle to receive an acknowledge signal.

During a write, the chip is always the receiver so that it outputs an acknowledge signal each time it has received eight bits of data.

During a read, the chip outputs an acknowledge signal after it receives an address following a start condition. Then, it outputs read data and releases the bus to wait for an acknowledge signal from the master. When it detects an acknowledge signal, it outputs data at the next address if it does not detect a stop condition. If the chip does not detect an acknowledge signal, it stops read operation, and enters the standby state when a stop condition occurs subsequently.

If the chip does not detect an acknowledge signal nor a stop condition, it keeps the bus released.

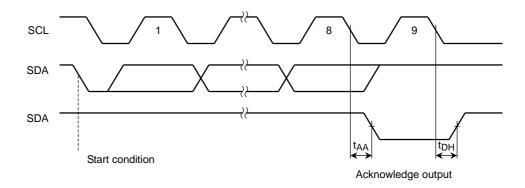


Figure 3

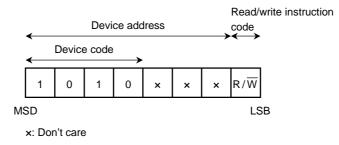
4. Device Addressing

After a start condition occurs, a 7-bit device address and a 1-bit read/write instruction code are input to the chip.

The upper four bits are called device code, which must always be "1010". The next three bits are used to select a device on the bus. These three bits are not specified for this IC and can be set to any value.

The least significant bit (R/\overline{W} : READ/ \overline{WRITE}) indicates a read instruction when set to 1 and a write instruction when set to 0.

An instruction is not executed if the device address does not match the specified value.





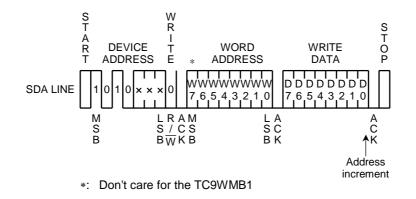
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5. Write Operation

(1) Byte write

A byte write writes data to a specified address. After a start condition, input a device address, R/\overline{W} (= 0), a word address, and write data.

When a stop condition is entered subsequently, write operation starts automatically, rewriting the data at the specified address with the input data. A next instruction cannot be accepted while write operation is in progress. Therefore, no acknowledge signal is returned. After writing the data, the chip automatically enters the standby state.





(2) Page write

A page write writes up to eight bytes of data collectively to a specified page. After a start condition, input a device address, R/\overline{W} (= 0), a word address (n), and write data (n), in the same way as for a byte write. Then, input write data (n + 1) immediately without entering a stop condition, while checking that an acknowledge signal is asserted (0).

The upper four bits (A3 to A6) of the word address are fixed and the lower three bits (A0 to A2) are automatically incremented so that up to eight bytes of data can be input.

When the last address within the page is reached, the lower three bits (A0 to A2) of the word address are rolled over to the first address of the page. If more than eight bytes of write data are input, the last eight bytes are valid.

When a stop condition is entered subsequently, write operation starts automatically, rewriting the data at the specified addresses with the input data.

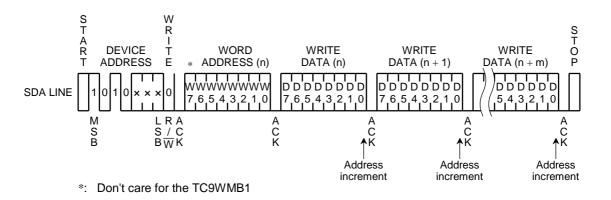


Figure 6

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(3) Acknowledge polling

Acknowledge polling is a feature for determining whether rewrite operation is in progress. During rewrite operation, input a start condition, a device address, and R/\overline{W} (= 0 or 1). The acknowledge feature does not output an acknowledge signal while rewrite operation is in progress. It outputs a low acknowledge signal if rewriting has already completed.

If the next instruction is a write, input a word address and write data subsequently. If the next instruction is a read, supply a stop condition and then start read operation.

(4) Write protection

Driving the write protection (WR) pin high causes the TC9WMB1FK to protect the entire memory area from being written and the TC9WMB2FK to protect the bottom half (80h to FFh) of the memory area from being written. Rewriting is allowed when the write protection pin is low. While a write is in progress, driving the WP pin high does not stop write operation.

Reading is always enabled regardless of whether the WP pin is high or low.

6. Read Operation

Read operation is performed in one of three modes: current address read, random read, and sequential read.

For reading, enter a device address and R/W (= 1) after a start condition. After read data is output, terminate read operation by inputting a high acknowledge signal (or releasing the bus without supplying an acknowledge signal) and then supplying a stop condition.

(1) Current address read

The internal address counter maintains the address that is next to the last accessed (read or written) word address (n). In current address read mode, data is read from address n + 1, as indicated by the address counter.

In current address read mode, entering a device address and R/W (= 1) after a start condition causes the chip to output a low acknowledge signal and then data at the address indicated by the internal address counter.

The address counter is incremented on a falling edge of the SCL pulse where the eighth bit is output. If the previous operation was reading data from the last address, the current address is rolled over to address 0. If the previous operation was writing data to the last address of the page, the address is rolled over to the first address of the page.

The current address is maintained in an internal register so that it is lost when the power is turned off. For the first read after power-up, specify an address by performing a random read.

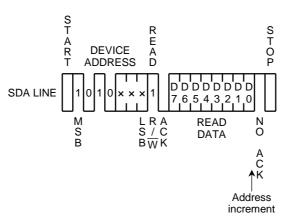


Figure 7

(2) Random read

A random read reads data at a specified address. A dummy write is necessary to specify an address. In random read mode, enter a device address, R/W (= 0), and a word address after a start condition. Unlike a byte or page write, where write data is entered immediately, a dummy write only specifies a word address. Then, supply a start condition and enter a device address and R/W (= 1) in the same way as for a current address read, to read data from the specified address.

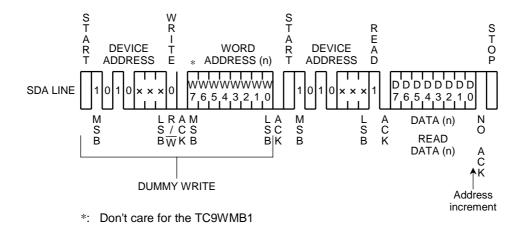


Figure 8

(3) Sequential read

A sequential read reads data sequentially from successive word addresses.

For either current address read or random read, after entering a start condition, a device address, and R/W (= 1), inputting a low acknowledge signal causes the word address to be incremented automatically to read data at the next address.

After the last address is reached, the word address is rolled over to address 0.

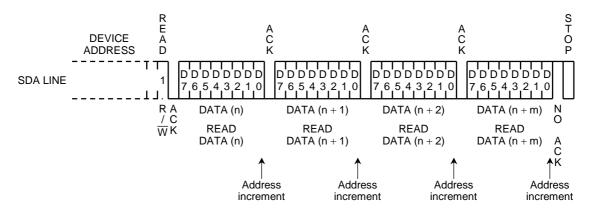


Figure 9

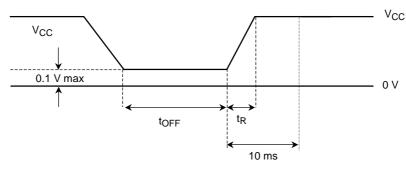
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7. Notes on Use

(1) Powering up the chip

This IC contains a power-on clear circuit, which initializes the internal circuit of the IC when the power is turned on. If initialization fails, the chip may malfunction. When powering up the chip, observe the following precautions to assure that the clear circuit will operate normally:

- (a) Pull SCL and SDA high.
- (b) The power rising time (tR) must be 10 ms or less.
- (c) After turning off the power, wait at least 100 ms (tOFF) before attempting to power up the chip again.
- (d) The supply voltage must rise from a voltage lower than 0.1 V.
- (e) After turning on the power, wait at least 10 ms before attempting to send an instruction to the chip.





- (2) Pulling up the SDA and SCL pins This IC requires the SDA and SCL pins to be pulled up with an external resistor. The recommended pull-up resistance range is 1 kΩ to 10 kΩ.
- (3) Noise elimination time for the SDA and SCL pins This IC contains a low-pass filter for eliminating noise on the SDA and SCL pins. Its guaranteed value corresponds to the noise suppression time Ti, given in the AC characteristics table.

Maximum Ratings (GND = 0 V)

Characteristics	Symbol	Rating	Units
Supply voltage	V _{CC}	-0.3~7.0	V
Input voltage	V _{IN}	$-0.3 \sim V_{CC} + 0.3$	V
Output voltage	V _{OUT}	$-0.3 \sim V_{CC} + 0.3$	V
Power dissipation	PD	200 (25°C)	mW
Storage temperature	T _{stg}	-55~125	°C
Operating temperature	T _{opr}	-40~85	°C

Recommended Operating Conditions (GND = 0 V, T_{opr} = -40 to 85°C)

Characteristics	Symbol	Test Condition	Min	Max	Unit	
Supply voltage (for reading)	V _{CC}	—	1.8	5.5	V	
Supply voltage (for writing)	V _{CC}	_	2.3	5.5	V	
High-level input voltage	VIH	$2.3 \text{ V} \leq \text{V}_{CC} \leq 5.5 \text{ V}$	$0.7 \times V_{CC}$	V _{CC}	V	
Hign-level input voltage	VIH	$1.8 \text{ V} \leq \text{V}_{CC} < 2.3 \text{ V}$	$0.8 \times V_{CC}$	V _{CC}	v	
Low-level input voltage	M.	$2.3 \text{ V} \leq \text{V}_{CC} \leq 5.5 \text{ V}$	0	$0.3 \times V_{CC}$	V	
Low-level input voitage	VIL	$1.8 \text{ V} \leq \text{V}_{CC} < 2.3 \text{ V}$	0	$0.2 \times V_{CC}$	V	
Operating frequency	faci	$2.3 \text{ V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{ V}$	0	400		
	f _{SCL}	$1.8 \text{ V} \leq \text{V}_{CC} < 2.3 \text{ V}$	0	100	kHz	

Electrical Characteristics

DC Characteristics (GND = 0 V, $T_{opr} = -40$ to 85° C)

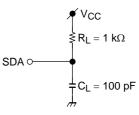
Characteristics	Symbol	Test	$1.8 \leqq V_{CC} < 2.3 \ V$		$2.3 \leqq V_{CC} \leqq 3.6 \text{ V}$		$4.5 \leq V_{CC} \leq 5.5 \ V$		Unit
Characteristics	Symbol	Condition	Min	Max	Min	Max	Min	Max	Unit
Input current	ILI	—	_	±1	_	±1	_	±1	μA
Output leakage current	I _{LO}	_		±1	_	±1		±1	μA
Low-level output voltage	Ve	I _{OL} = 3.2 mA		_	—	0.4		0.4	V
Low-level output voltage	V _{OL}	I _{OL} = 1.5 mA		0.5	—	_		_	v
Quiescent supply current	I _{CC1}	—		5	_	5		5	μA
Supply current during read	I _{CC2}	f = 400 kHz		0.2*		0.3		0.5	mA
Supply current during write	I _{CC3}	f = 400 kHz				1.5		2.0	mA

*f = 100 kHz

AC Characteristics (GND = 0 V, $T_{opr} = -40$ to 85° C)

Test Conditions

Input pulse voltage	$0.1 \times V_{CC}\text{-}0.9 \times V_{CC}$		
Input rise/fall time	20 ns		
Input/output testing voltage	$0.5 imes V_{CC}$		
Output load	100 pF + 1 k Ω pull-up resistor		



Characteristics	Symbol	$1.8 \leq V_C$	_C < 2.3 V	$2.3 \stackrel{\scriptstyle \leq}{=} V_{CC} \stackrel{\scriptstyle \leq}{=} 3.6 \ V$		$4.5 \stackrel{\scriptstyle \leq}{=} V_{CC} \stackrel{\scriptstyle \leq}{=} 5.5 \ V$		Unit
Characteristics	Symbol	Min	Max	Min	Max	Min	Max	Unit
SCL clock frequency	f _{SCL}	0	100	0	400	0	400	kHz
SCL clock "low" time	t _{LOW}	4.7	_	1.2	_	1.2	_	μs
SCL clock "high" time	thigh	4.0	_	0.6	_	0.6	_	μs
Noise suppression time	tı		100		50	_	50	ns
SDA output delay	t _{AA}	0.1	4.5	0.1	0.9	0.1	0.9	μs
Bus free time	t _{BUF}	4.7	_	1.2	_	1.2	_	μs
Start condition hold time	^t HD.STA	4.0	_	0.6	_	0.6	_	μs
Start condition setup time	^t SU.STA	4.7		0.6	—	0.6		μs
Data input hold time	^t HD.DAT	0	_	0		0	_	ns
Data input setup time	^t SU.DAT	250	_	200	—	200	_	ns
SCL, SDA input rise time	t _R		1.0		0.3	_	0.3	μs
SCL, SDA input fall time	t _F		0.3		0.3	_	0.3	μs
Stop condition setup time	tsu.sto	4.7	_	0.6		0.6		μs
SDA output hold time	^t DH	100	_	50	—	50	_	ns

E^2PROM Characteristics (GND = 0 V, 2.3 V \leq V_{CC} \leq 2.7 V, T_{opr} = –40 to 85°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Write time	t _{WR}	—	_		12	ms
Rewrite endurance	N _{EW}	—	1×10^5	_		Times
Data retention time	t _{RET}	_	10		_	Years

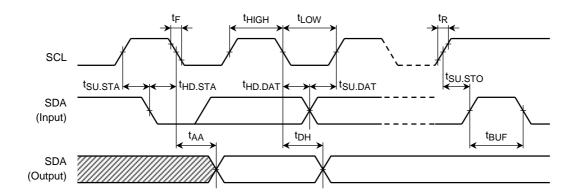
E^2PROM Characteristics (GND = 0 V, 2.7 V < V_{CC} \leq 5.5 V, T_{opr} = –40 to 85°C)

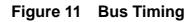
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Write time	t _{WR}	—	_	_	10	ms
Rewrite endurance	NEW		1×10^5	_	_	Times
Data retention time	t _{RET}	_	10	_	_	Years

Capacitance Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_	5.0	4	pF
Output capacitance	CO	_	5.0	3	pF

AC Characteristics Timing Charts





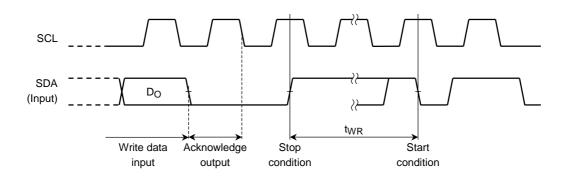


Figure 12 Write Cycle Timing

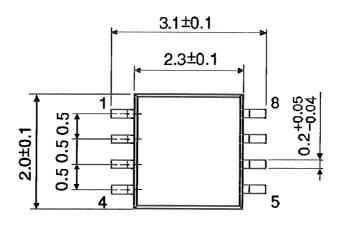
Input/Output Circuits of Pins

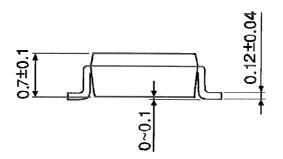
Pin	Туре	Input/Output Circuit	Remarks
WP	Input		_
SCL	Input		_
SDA	Input/output		Open-drain output

Package Dimensions

SSOP8-P-0.50A

Unit : mm





Weight: 0.01 g (typ.)

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Handbook" etc..

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